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ECH8660

Power MOSFET

30V, 4.5A, 59mΩ, -30V, -4.5A, 59mΩ, Complementary Dual ECH8

ON Semiconductor®

<http://onsemi.com>

Features

- The ECH8660 incorporates an N-channel MOSFET and a P-channel MOSFET that feature low ON-resistance and high-speed switching , thereby enabling high-density mounting
- 4V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

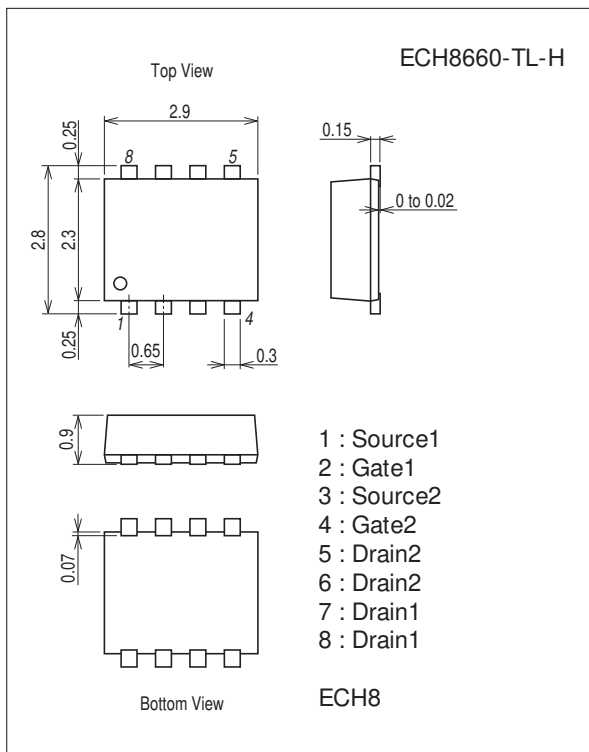
Parameter	Symbol	Conditions	N-channel	P-channel	Unit
Drain-to-Source Voltage	V _{DSS}		30	-30	V
Gate-to-Source Voltage	V _{GSS}		±20	±20	V
Drain Current (DC)	I _D		4.5	-4.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	30	-30	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (1200mm ² ×0.8mm) 1unit	1.3		W
Total Dissipation	P _T	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.5		W
Channel Temperature	T _{ch}		150		°C
Storage Temperature	T _{stg}		-55 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

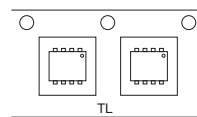
7011A-001



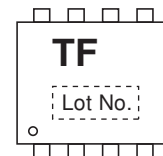
Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

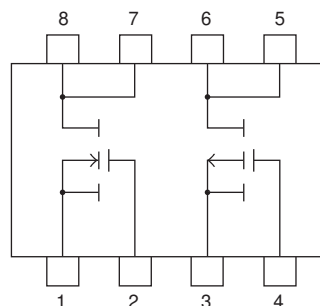
Packing Type : TL



Marking



Electrical Connection



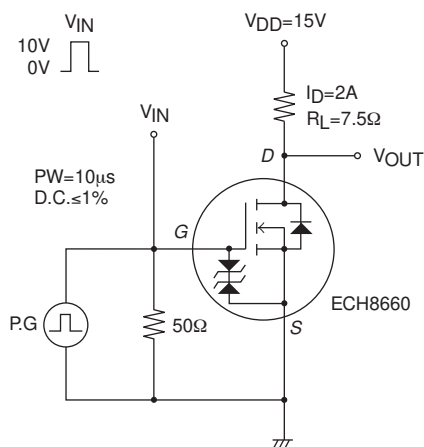
ECH8660

Electrical Characteristics at Ta=25°C

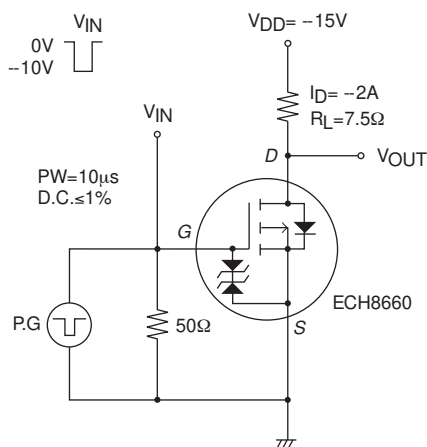
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[N-channel]						
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16V, V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	1.2		2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=2A$	1	1.66		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=2A, V_{GS}=10V$		45	59	$m\Omega$
	$R_{DS(on)2}$	$I_D=1A, V_{GS}=4.5V$		85	119	$m\Omega$
	$R_{DS(on)3}$	$I_D=1A, V_{GS}=4V$		110	155	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS}=10V, f=1MHz$		240		pF
Output Capacitance	C_{oss}	$V_{DS}=10V, f=1MHz$		45		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=10V, f=1MHz$		30		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		6.2		ns
Rise Time	t_r	See specified Test Circuit.		11		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		17		ns
Fall Time	t_f	See specified Test Circuit.		7.5		ns
Total Gate Charge	Q_g	$V_{DS}=10V, V_{GS}=10V, I_D=4.5A$		4.4		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=10V, V_{GS}=10V, I_D=4.5A$		1.1		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=10V, V_{GS}=10V, I_D=4.5A$		0.64		nC
Diode Forward Voltage	V_{SD}	$I_S=4.5A, V_{GS}=0V$		0.84	1.2	V
[P-channel]						
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=-1mA, V_{GS}=0V$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16V, V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-10V, I_D=-1mA$	-1.2		-2.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10V, I_D=-2A$	2.5	4.2		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-2A, V_{GS}=-10V$		45	59	$m\Omega$
	$R_{DS(on)2}$	$I_D=-1A, V_{GS}=-4.5V$		71	100	$m\Omega$
	$R_{DS(on)3}$	$I_D=-1A, V_{GS}=-4V$		82	115	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS}=-10V, f=1MHz$		430		pF
Output Capacitance	C_{oss}	$V_{DS}=-10V, f=1MHz$		105		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=-10V, f=1MHz$		75		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		7.5		ns
Rise Time	t_r	See specified Test Circuit.		26		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		45		ns
Fall Time	t_f	See specified Test Circuit.		35		ns
Total Gate Charge	Q_g	$V_{DS}=-10V, V_{GS}=-10V, I_D=-4.5A$		10		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=-10V, V_{GS}=-10V, I_D=-4.5A$		2.0		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=-10V, V_{GS}=-10V, I_D=-4.5A$		2.5		nC
Diode Forward Voltage	V_{SD}	$I_S=-4.5A, V_{GS}=0V$		-0.85	-1.2	V

Switching Time Test Circuit

[N-channel]

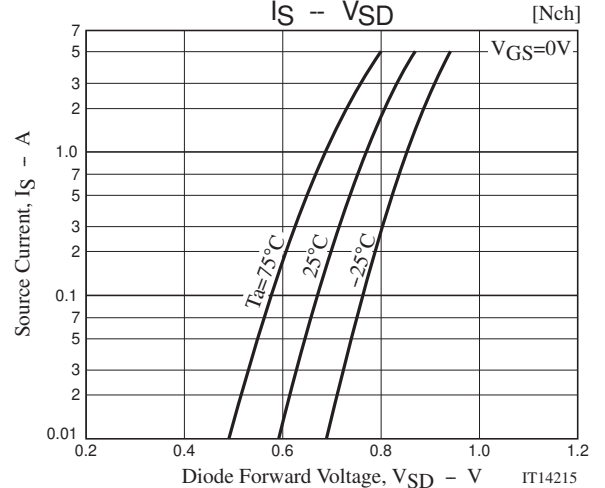
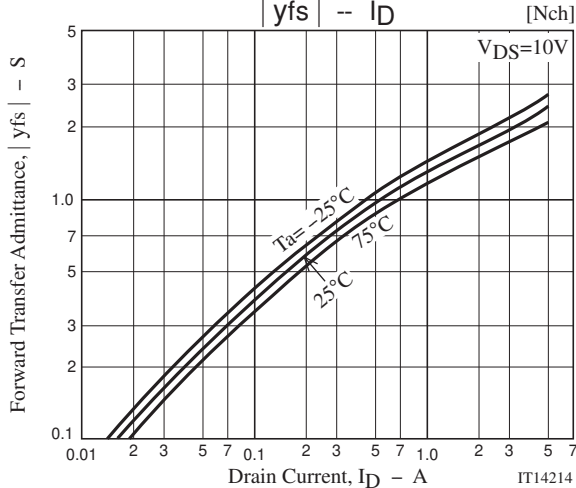
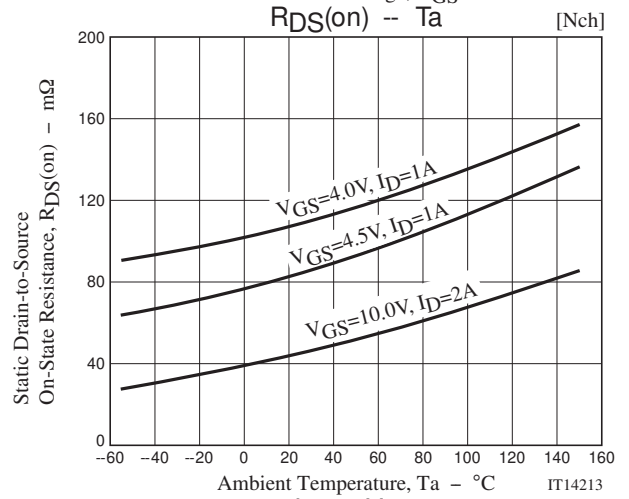
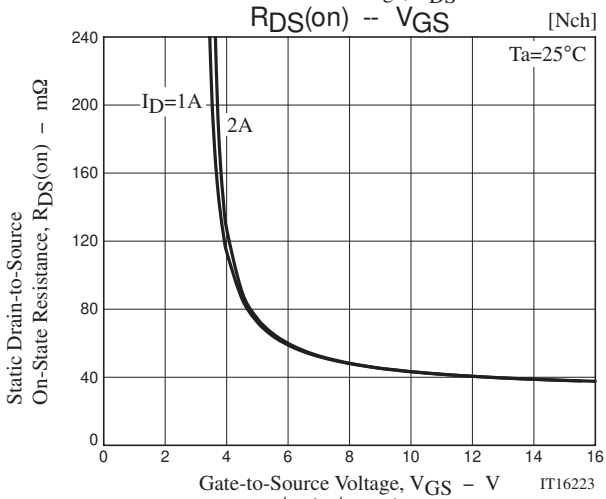
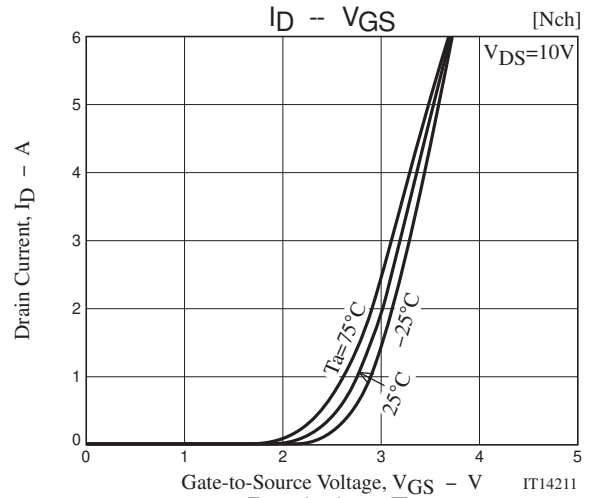
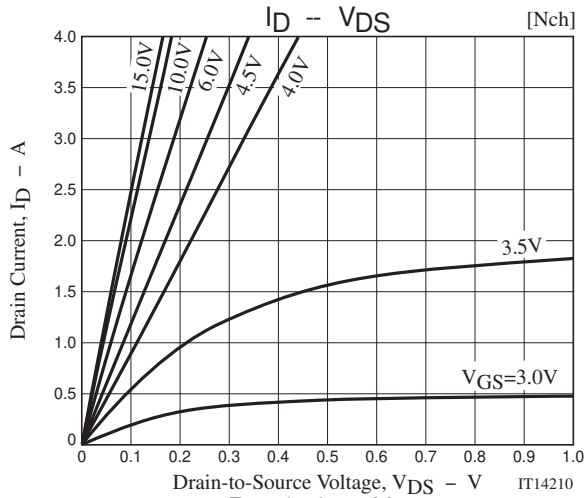


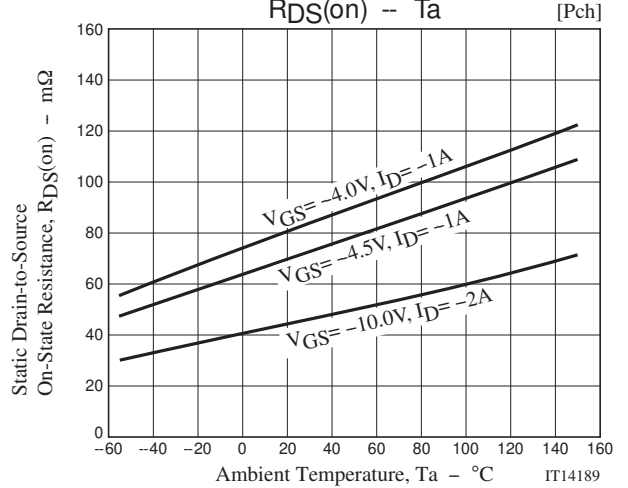
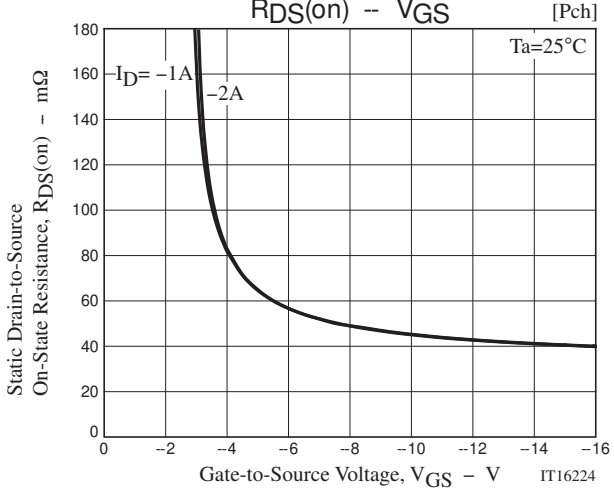
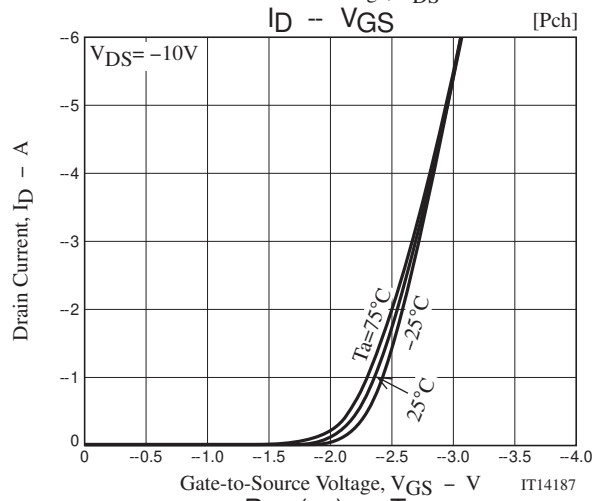
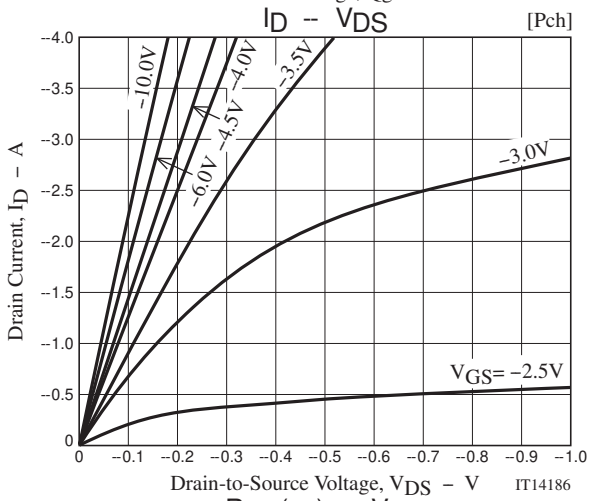
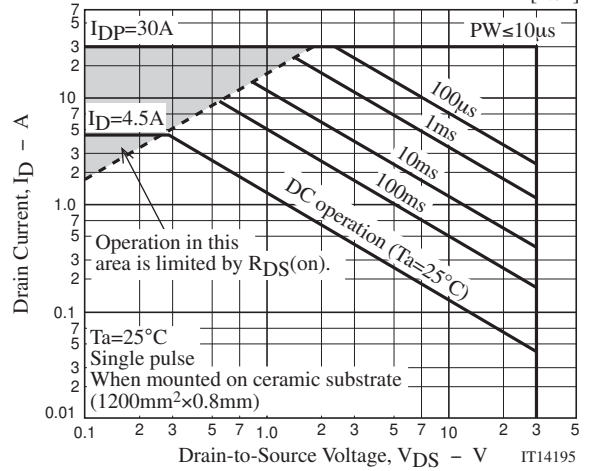
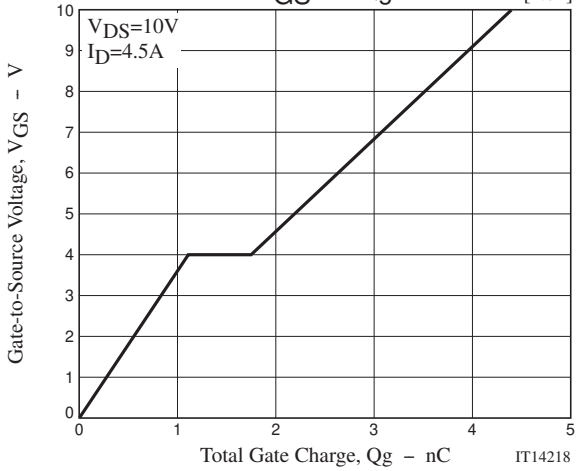
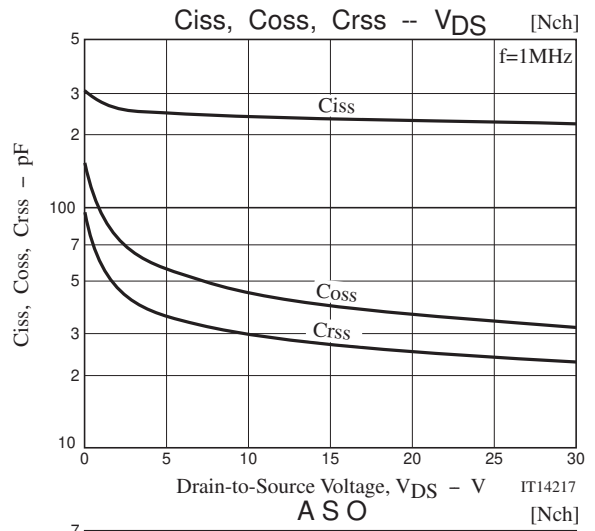
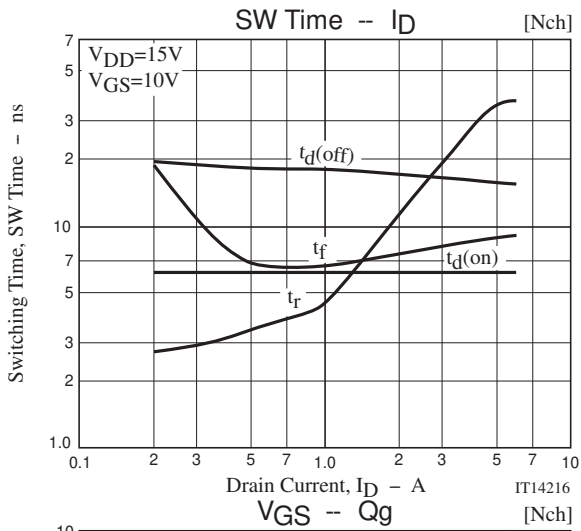
[P-channel]

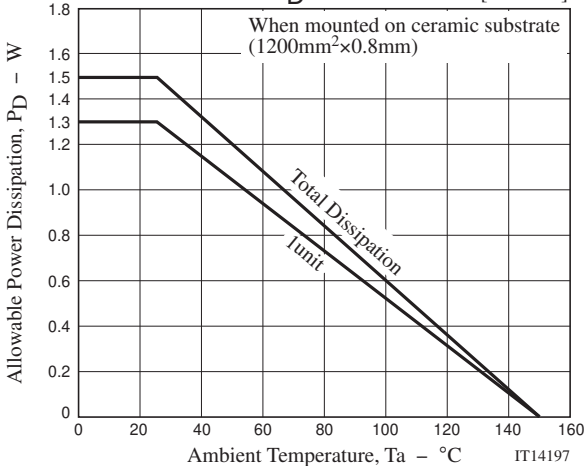
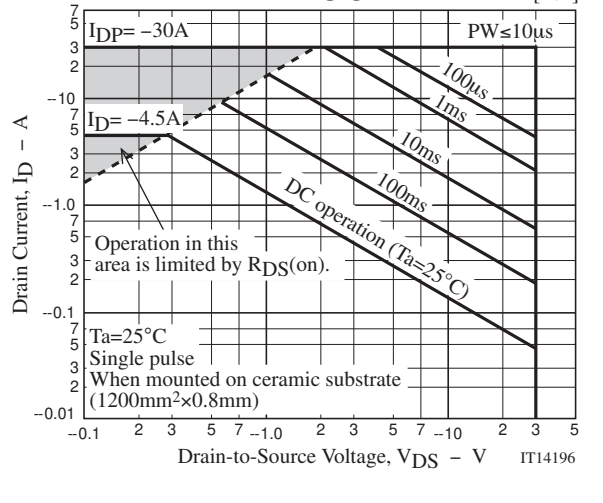
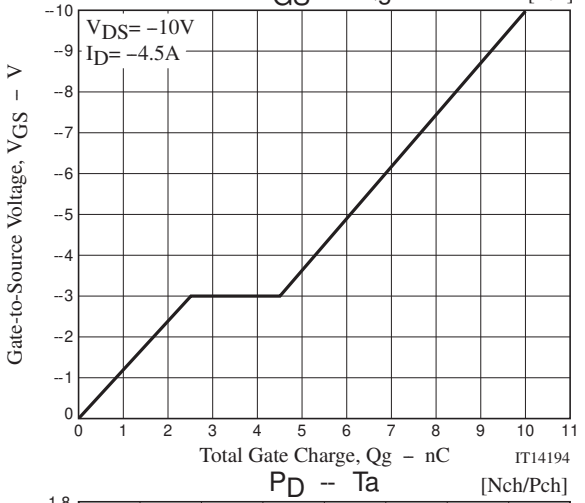
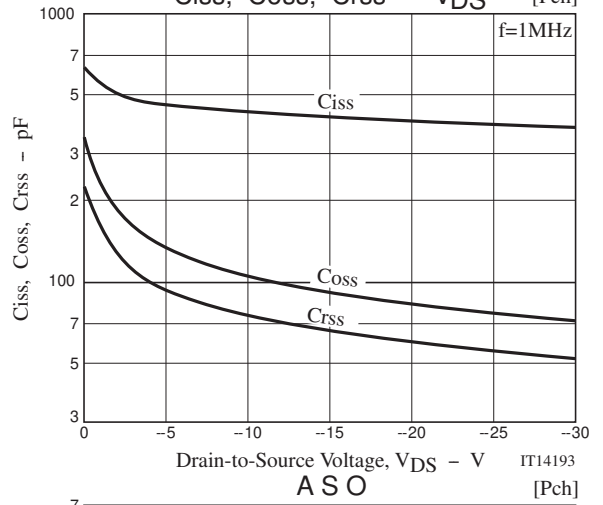
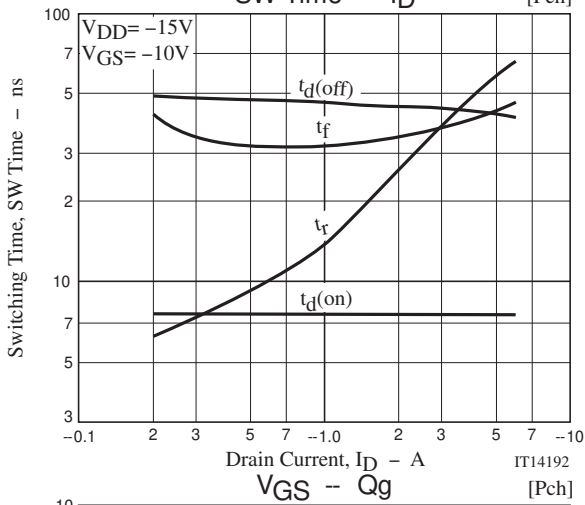
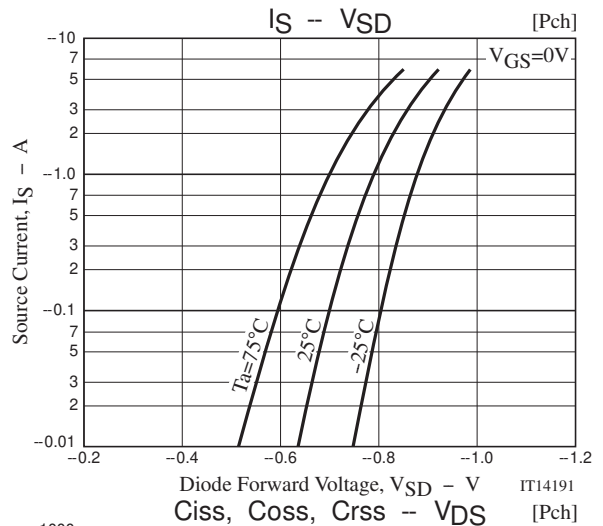
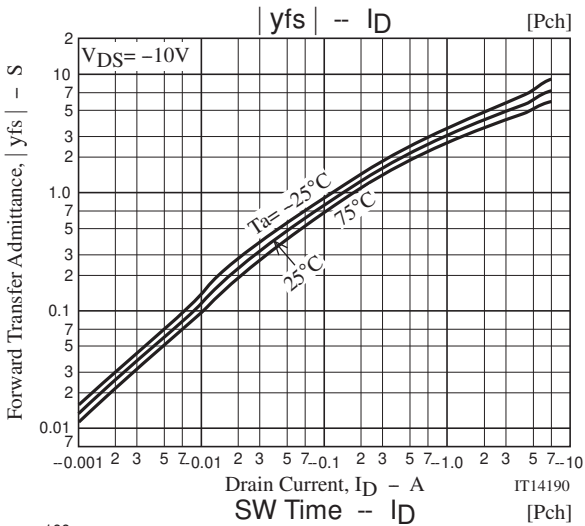


Ordering Information

Device	Package	Shipping	memo
ECH8660-TL-H	ECH8	3,000pcs./reel	Pb-Free and Halogen Free







Embossed Taping Specification

ECH8660-TL-H

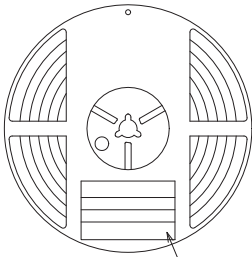
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

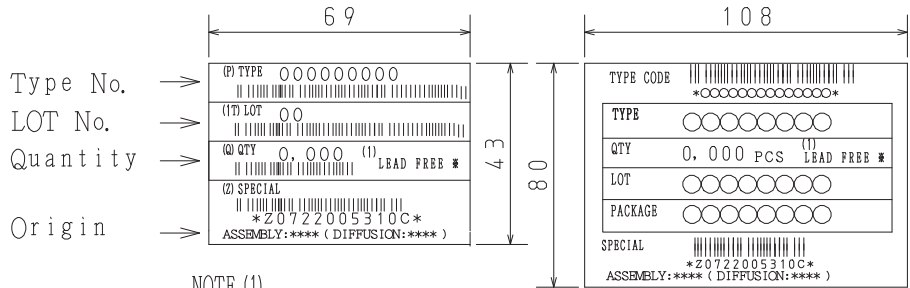
Reel label, Inner box label
(unit :mm)

Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label



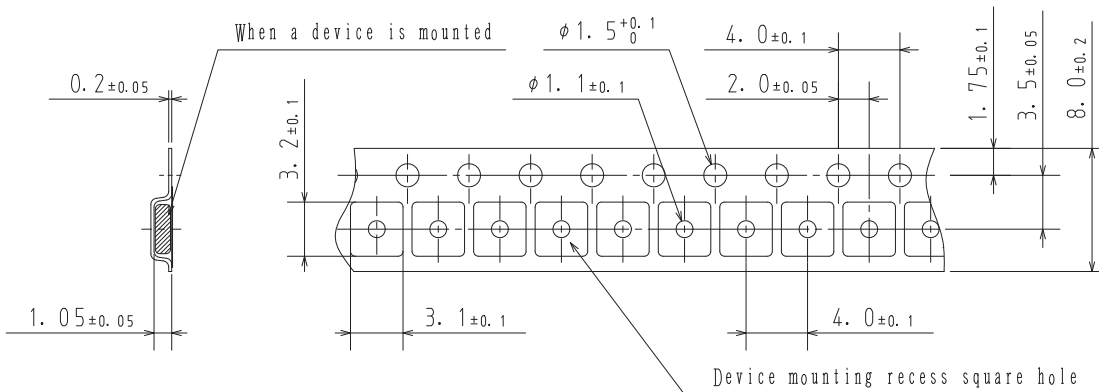
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

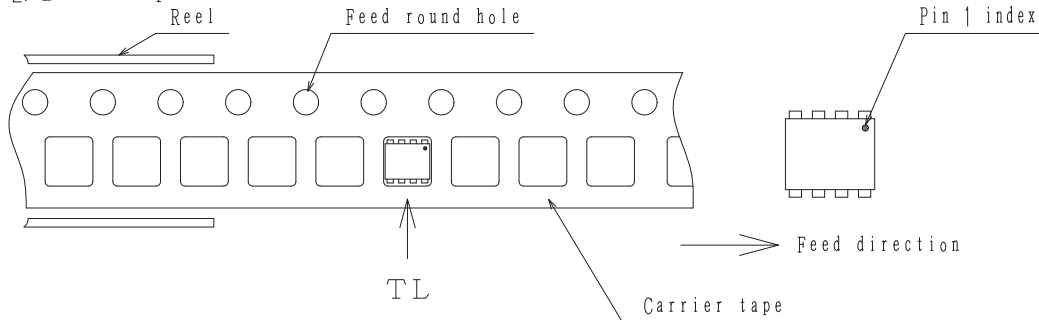
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

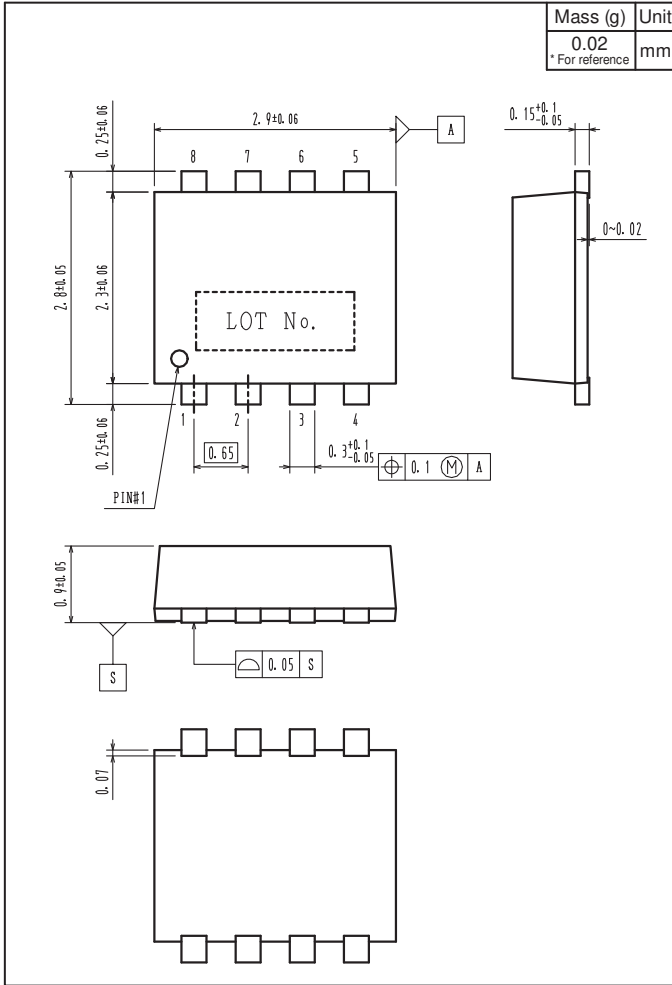


Those with pin 1 index on the feed hole side.....TL

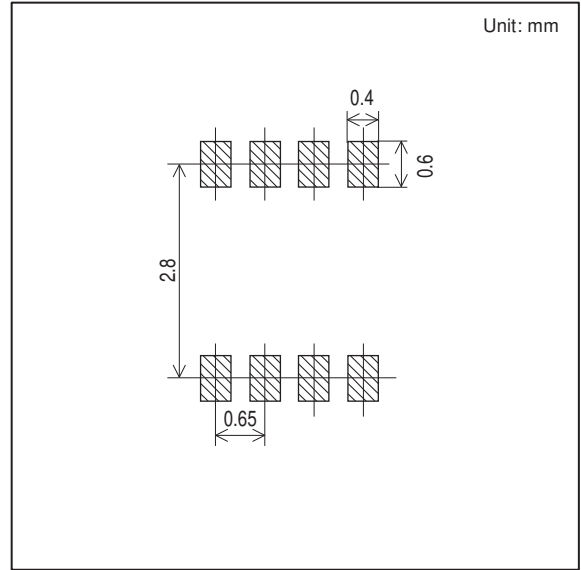
ECH8660

Outline Drawing

ECH8660-TL-H



Land Pattern Example



Note on usage : Since the ECH8660 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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